

8kV 400mA HIGH VOLTAGE DIODE

CL03-08 is high reliability resin molded type high voltage diode in small size package which is sealed a multilayed mesa type silicon chip by epoxy resin.

■ Features

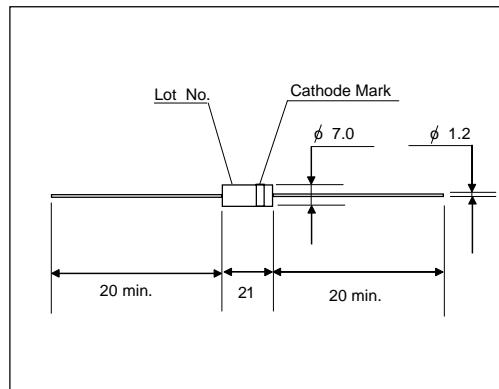
- High speed switching
- Low VF
- High surge resistivity for CRT discharge
- High reliability design
- Ultra small pakage

■ Applications

- X light Power supply
- Laser
- Voltage doubler circuit
- Microwave emission power

■ Maximum Ratings and Characteristics

- Absolute Maximum Ratings

■ Outline Drawings : mm**■ Cathode Mark**

Type	Mark
CL03-08	

Items	Symbols	Condition	CL03-08	Units
Repetitive Peak Renerse Voltage	V _{RRM}		8	kV
Average Output Current	I _o	T _a =25°C, Resistive Load	400	mA
Suege Current	I _{FSM}		15	A _{peak}
Junction Temperature	T _j		155	°C
Allowable Operation Case Temperature	T _c		125	°C
Storage Temperature	T _{stg}		-40 to +155	°C

- Electrical Characteristics (T_a=25°C Unless otherwise specified)

Items	Symbols	Conditions	CL03-08	Units
Maximum Forward Voltage Drop	V _F	at 25°C, I _f =I _{F(AV)}	25	V
Maximum Reverse Current	IR1	at 25°C, VR=V _{RRM}	5.0	μA
	IR2	at 100°C, VR=V _{RRM}	50	μA
Maximum Reverse Recovery Time	T _{rr}	at 25°C	100	nS
Junction Capacitance	C _j	at 25°C, V _R =0V, f=1MHz	15	pF